## NSN 5961-01-084-5549

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-084-5549 **Inclosure Material:** Metal **Overall Length:** Between 0.515 inches and 0.565 inches **Overall Diameter:** Between 1.600 inches and 1.650 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 225.00 amperes forward current, total rms torr **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 1 ferrule and 2 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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